

Real-space calculations to obtain a quantitative understanding of the electronic structure of layered materials such as tBG, tNG, GBN and hBN encapsulated BG

Twistronics 2023

Advisor: Prof. GJ Jung Collaborators: JQ An, YJ Park, S Javvaji, A Samudrala

Nicolas Leconte University of Seoul

Direct observation of flat bands in twisted bilayer graphene

- Experimental ARPES observation
- Multi-scale approach to match experimental observations

Visualization of the flat electronic band in twisted bilayer graphene near the magic angle twist

M. Iqbal Bakti Utama @1,2,3,10, Roland J. Koch @4,10, Kyunghoon Lee @1,1,10, Nicolas Leconte ^{@5}, Hongyuan Li^{1,6}, Sihan Zhao^o, Lili Jiang¹, Jiayi Zhu¹, Kenji Watanabe^o⁷, Takashi Taniguchi⁷, Paul D. Ashby^{®®}, Alexander Weber-Bargioni[®], Alex Zettl^{1,3,9}, Chris Jozwiak^{®®}, Jeil Jung^{®552}, Eli Rotenberg⁰⁴, Aaron Bostwick⁰⁴⁵² and Feng Wang⁰¹³⁹⁵²

Real-space multiscale methodology

Multi-scale approach

vdW physics with a covalent flavor: atoms try to hybridize to minimize their energies

DFT calculations:

- Accuracy, computationally expensive
- Appropriate scheme (LDA, RPA, etc)
- $\begin{array}{c} \text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{F}_{\text{F}}\text{$

(Accurate continuum models)

Real-space tight-binding (TB) model

- Compare rigid and relaxed structures
- **Flectronic band structure**
- Spectral function
- Electronic transport

- Rebo, Tersoff,... intralayer potentials
- Machine learning potentials (Gap20)

Energy minimizations

- Use LAMMPS (or Gromacs, or...)
- Quantify relaxation effects such as Large scale TB simulations:
attice reconstruction, corrugation, etc

Relaxation effects in twisted bilayer graphene: A multiscale approach

Nicolas Leconte, Srivani Javvaji, Jiagi An, Appalakondaiah Samudrala, and Jeil Jung Phys. Rev. B 106, 115410 - Published 12 September 2022

Pairwise potential

- Lennard-Jones

LAMMPS...

Pairwise potential

Lennard-Jones $\overline{}$

Kolmogorov-Crespi $\overline{}$

Pairwise potential

Lennard-Jones

Kolmogorov-Crespi

DRIP (dihedral-angle-corrected registry-dependent) Potential $\overline{}$

Mingjian Wen, Stephen Carr, Shiang Fang, Efthimios Kaxiras, and Ellad B. Tadmor PHYSICAL REVIEW B98, 235404 (2018)

$$
\phi_{ij} = f_c(x_r) \left[e^{-\lambda (r_{ij} - z_0)} \left[C + f(\rho_{ij}) + g(\rho_{ij}, {\alpha}_{ij}^{(m)}) \right] - A \left(\frac{z_0}{r_{ij}} \right)^6 \right]
$$

$$
E = \frac{1}{2} \sum_{i} \sum_{j \notin \text{layer } i} \phi_{ij}
$$

FIG. 2. Schematic representation of an atomic geometry that defines the normal vectors n_i and n_j and the dihedral angle $\Omega_{k_1ijk_2}$.

2E.03 1.083

 $2535111E.031522$

 $\bullet - \bullet$ KC

 \triangle - \triangle DRIP

 60

TB models: interlayer and intralayer terms

Intralayer:

- Use F2G2 models to simulate intralayer terms of hBN, G, BG, etc systems
- Add moire induced-intralayer modifications of onsite energies and first-nearest neighbor hopping terms

Interlayer:

- Modified two center approximation models for interlayer hoppings

F2G2 Models

- Wannierization of the pi-orbitals centered around the carbon atoms…
- Long-range interactions are reduced to relatively short-range effective models that capture the DFT pi-bands

Accurate tight-binding models for the π bands of bilayer graphene

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Department of Physics, University of Texas at Austin, Austin, Texas 78712-0264, USA (Received 20 September 2013; revised manuscript received 12 December 2013; published 6 January 2014)

 $H = |H_{\text{intra}}| + H_{\text{inter}}.$

 $\text{TR Hamiltonian} \qquad \qquad H = \overline{H_{\text{intra}}} + H_{\text{inter}}.$ Average from AA, AB and BA

commensurate cell DFT calcu

$$
H_{\text{intra}} = H_{\text{intra}}^{\text{F2G2}} + H_{\text{intra}}^{\text{virtual strain}}
$$

commensurate cell DFT calculations

$$
H_{ii}(\boldsymbol{d}_{ij}:\mathbf{K})=\sum_{n} t_{ii_n}(\boldsymbol{d}_{ij})g_n(\mathbf{K})
$$

$$
H_{ij}(\boldsymbol{d}_{ij}:\mathbf{K})=\sum_{n} t_{ij_n}(\boldsymbol{d}_{ij})f_n(\mathbf{K})
$$

 $H = |H_{\text{intra}}| + H_{\text{inter}}.$

$H_{\text{intra}} = H_{\text{intra}}^{\text{F2G2}}$ $H_{intra}^{virtual strain}$

Average from AA, AB and BA commensurate cell DFT calculations

$$
H_{ii}(\boldsymbol{d}_{ij}:\mathbf{K})=\sum_{n} t_{ii_n}(\boldsymbol{d}_{ij})g_n(\mathbf{K})
$$

$$
H_{ij}(\boldsymbol{d}_{ij}:\mathbf{K})=\sum_{n} t_{ij_n}(\boldsymbol{d}_{ij})f_n(\mathbf{K})
$$

Moire bands

Take information from different local stacking configurations in the unit cell

$$
H_{\text{onsite}} = H_{ii} \mid \text{ for } g_0 = 1
$$

$$
H_{\text{onsite}}(\vec{d}) = C_{0ii} + 2C_{1ii} \text{Re}\left[f(\vec{d}) \exp(i\phi_{ii})\right]
$$

$$
ii = C_1, C_2, B \text{ or } N
$$

$$
f(\vec{d}) = \exp(-iG_1d_y) + 2\exp\left(i\frac{G_1d_y}{2}\right)\cos\left(\frac{\sqrt{3}}{2}G_1d_x\right)
$$

$$
H = H_{\text{intra}} + H_{\text{inter}}.
$$

$$
H_{\text{intra}} = H_{\text{intra}}^{\text{F2G2}} + H_{\text{intra}}^{\text{virtual strain}}
$$

$$
\frac{\frac{a}{H_{c,c}} \frac{b}{B \cdot 0.1241 \cdot 1178} \cdot \frac{c}{2.151}}{B \cdot \frac{c}{2.121 \cdot 11.125} \cdot \frac{c}{2.513}}}{\frac{b}{H_{c,c}} \frac{c}{B \cdot 0.028 \cdot 11.25} \cdot \frac{c}{2.513}} \cdot \frac{c}{2.513}}}{\frac{b}{H_{B}} \frac{c}{B \cdot 0.239 \cdot 2.204}} \cdot \frac{c}{2.513 \cdot 11.25} \cdot \frac{c}{2.513}} \cdot \frac{d}{2.513}
$$
\n
$$
= a(c^{\perp})^2 + bc^{\perp} + c
$$
\n
$$
\frac{b}{H_{B}} \frac{c}{B \cdot 0.292 \cdot 14.097 \cdot 25.568}} \cdot \frac{d}{2.204} \cdot \frac{d}{2.206}
$$
\n
$$
\frac{d}{H_{B}} \frac{d}{B \cdot 0.1288 \cdot 11.25} \cdot \frac{c}{2.5135}} \cdot \frac{d}{2.208}
$$
\n
$$
= arctan \left[-\frac{\sqrt{3}}{2(D+1/2)} \right]
$$
\n
$$
C_{1ii} = (C - B)/6\sqrt{3} \sin \phi
$$
\n
$$
C_{0ii} = -6C_1 \cos \phi + A
$$
\n
$$
C_{0ii} = -6C_1 \cos \phi + A
$$
\n
$$
C_{0ii} = \frac{c}{2.00400 \cdot 10.3679 \cdot 10.427 \cdot 10.4
$$

$$
H = H_{\text{intra}} + H_{\text{inter}}.
$$

-

$$
H_{\text{intra}} = H_{\text{intra}}^{\text{F2G2}} + H_{\text{intra}}^{\text{virtual strain}}
$$

 $\frac{2}{\sqrt{3}}$
 $\frac{2}{\sqrt{3}}$

 $\mathsf{Re}\left[H_{C_1C_2}(\vec{d})\right]_{\text{(meV)}}\text{Im}\left[H_{C_1C_2}(\vec{d})\right]_{\text{(meV)}}\text{Re}\left[H_{BN}(\vec{d})\right]_{\text{(meV)}}\text{Im}\left[H_{BN}(\vec{d})\right]_{\text{(meV)}}$

$$
H = H_{\text{intra}} + \boxed{H_{\text{inter}}}.
$$

$$
t_{\text{model},ij}^{\text{inter}} = \exp\left[\frac{r_z - p}{q}\right] t_{\text{TC},ij}^{\text{inter}}
$$

$$
t_{\text{TC},ij}^{\text{inter}} = V_{pp\pi}(r_{ij}) \left[1 - \left(\frac{r_z}{r_{ij}}\right)^2 \right] + V_{pp\sigma}(r_{ij}) \left(\frac{r_z}{r_{ij}}\right)^2
$$

$$
V_{pp\pi}(r_{ij}) = V_{pp\pi}^{0} \exp\left(-\frac{r_{ij} - a_{CC}}{r_{0}}\right)
$$

$$
V_{pp\sigma}(r_{ij}) = V_{pp\sigma}^{0} \exp\left(-\frac{r_{ij} - c_{0}}{r_{0}}\right)
$$

$$
H_{ss'}(\boldsymbol{K}:\boldsymbol{d})=\sum_{j_{s'}}t_{i_s\,j_{s'}}^{\text{inter}}\exp\left[\mathrm{i}\boldsymbol{K}\cdot(\boldsymbol{d}+\boldsymbol{r}_{i_s\,j_{s'}})\right]
$$

Magic angle renormalization in tBG

$$
t_{\text{SHE},ij} = \begin{cases} t_{\text{F3G2},ij}^{\text{intra}} & \text{if } i \in \text{ layer } j\\ S \exp\left[(c_{ij} - p)/q \right] t_{\text{TC},ij}^{\text{inter}} & \text{if } i \notin \text{ layer } j \end{cases}
$$

Hybrid neural network potential for multilayer graphene

Mingjian Wen¹ and Ellad B. Tadmor^{1,*}

 1 Department of Aerospace Engineering and Mechanics, University of Minnesota, Minneapolis, MN 55455, USA (Dated: November 19, 2019)

A Review on Mechanics and Mechanical Properties of 2D Materials -**Graphene and Beyond**

Intra-layer force field effect

Deji Akinwande¹, Christopher J. Brennan¹, J. Scott Bunch², Philip Egberts³, Jonathan R. Felts⁴, Huajian Gao⁵, Rui Huang^{6*}, Joon-Seok Kim¹, Teng Li⁷, Yao Li⁸, Kenneth M. Liechti^{6*}, Nanshu Lu⁶, Harold S. Park², Evan J. Reed⁹, Peng Wang⁶, Boris I. Yakobson¹⁰, Teng Zhang¹¹, Yong-Wei Zhang¹², Yao Zhou⁹, Yong Zhu¹³

Table I. Linearly elastic properties of monolayer graphene predicted by first principles and empirical potential based calculations.

Improved intra-layer with EXX-RPA informed interlayer

An accurate and transferable machine learning potential for carbon

J. Chem. Phys. 153, 034702 (2020); https://doi.org/10.1063/5.0005084

D Patrick Rowe¹, **D** Volker L. Deringer², **D** Piero Gasparotto¹, **D** Gábor Csányi³, and **D** Angelos Michaelides^{1,a)}

Building the commensurate cell

Figure 2. Definition of lattice vectors and angles of the substrate, \underline{R}_{01} , \underline{R}_{02} , ω , of the overlayer, \underline{R}'_{01} , \underline{R}'_{02} , and of the moiré lattice, $\underline{R}_{M1}, \underline{R}_{M2}, \gamma_1, \gamma_2.$

$$
M = \begin{pmatrix} a & b \\ -b & a+b \end{pmatrix}, M' = \begin{pmatrix} a' & b' \\ -b' & a'+b' \end{pmatrix}, \begin{pmatrix} R_1 \\ R_2 \end{pmatrix} = M \begin{pmatrix} R_{o1} \\ R_{o2} \end{pmatrix} = M' \begin{pmatrix} R'_{o1} \\ R'_{o2} \end{pmatrix}
$$

1

$$
\cos(\alpha) = \frac{1}{2p\Gamma} \left[2a'a + 2b'b + a'b + b'a \right] \quad p = \sqrt{\frac{a^2 + b^2 + a'b}{a^2 + b^2 + ab}}
$$

[1] K. Hermann, Journal of Physics: Condensed Matter 24, 314210 (2012).

Supermoire commensurate cells (e.g. hBN encapsulated BG)

$$
\begin{pmatrix}\mathbf{r}_1 \\ \mathbf{r}_2\end{pmatrix} = \mathbf{M}_1 \cdot \begin{pmatrix}\mathbf{a}_1 \\ \mathbf{a}_2\end{pmatrix} = \mathbf{M}_{2/3} \cdot \begin{pmatrix}\mathbf{a}'_1 \\ \mathbf{a}'_2\end{pmatrix} = \mathbf{M}_4 \cdot \begin{pmatrix}\mathbf{a}''_1 \\ \mathbf{a}''_2\end{pmatrix}
$$

$$
\mathbf{M}_1 = \begin{pmatrix} i & j \\ -j & i+j \end{pmatrix},
$$

\n
$$
\mathbf{M}_{2/3} = \begin{pmatrix} i' & j' \\ -j' & i'+j' \end{pmatrix},
$$

\n
$$
\mathbf{M}_4 = \begin{pmatrix} i'' & j'' \\ -j'' & i''+j'' \end{pmatrix}.
$$

$$
\alpha_{12} = \frac{|\mathbf{a}_1|}{|\mathbf{a}'_1|} = \sqrt{\frac{i'^2 + j'^2 + i'j'}{i^2 + j^2 + ij}},
$$

\n
$$
\alpha_{43} = \frac{|\mathbf{a}_1''|}{|\mathbf{a}'_1|} = \sqrt{\frac{i'^2 + j'^2 + i'j'}{i''^2 + j''^2 + i''j''}},
$$

\n
$$
\theta_{12} = \theta_1 - \theta_2 = \cos^{-1}\left[\frac{2ii' + 2jj' + ij' + ji'}{2\alpha_{12}(i^2 + j^2 + ij)}\right],
$$

\n
$$
\theta_{43} = \theta_4 - \theta_3 = \cos^{-1}\left[\frac{2i''i' + 2j''j' + i''j' + j''i'}{2\alpha_{43}(i''^2 + j''^2 + i''j'')}\right]
$$

Electronic structure of lattice relaxed alternating twist tNG-multilayer graphene

Experiments

Published: 05 March 2018

Unconventional superconductivity in magic-angle graphene superlattices

Yuan Cao ⊠, Valla Fatemi, Shiang Fang, Kenji Watanabe, Takashi Taniguchi, Efthimios Kaxiras & Pablo Jarillo-Herrero[□]

Nature 556, 43-50 (2018) Cite this article

187k Accesses | 2594 Citations | 638 Altmetric | Metrics

nature materials

ARTICLES https://doi.org/10.1038/s41563-022-01287-1

Check for updates

Robust superconductivity in magic-angle multilayer graphene family

Jeong Min Park ^{® 1,3} ⊠, Yuan Cao^{1,3}, Li-Qiao Xia [®]¹, Shuwen Sun¹, Kenji Watanabe ^{® 2}, Takashi Taniguchi[®] and Pablo Jarillo-Herrero^{®1⊠}

Article

Tunable strongly coupled superconductivity in magic-angle twisted trilayer graphene

Pablo Jarillo-Herrero¹⁵

Jeong Min Park^{1,4}, Yuan Cao^{1,452}, Kenii Watanabe², Takashi Taniguchi³ &

https://doi.org/10.1038/s41586-021-03192-0 Received: 26 October 2020 Accepted: 5 January 2021

Published online: 01 February 2021 Check for undates

Moiré superlattices^{1,2} have recently emerged as a platform upon which correlated physics and superconductivity can be studied with unprecedented tunability³⁻⁶. Although correlated effects have been observed in several other moiré systems7-17, magic-angle twisted bilaver graphene remains the only one in which robust superconductivity has been reproducibly measured⁴⁻⁶. Here we realize a moiré superconductor in magic-angle twisted trilayer graphene (MATTG)¹⁸, which has better tunability of its electronic structure and superconducting properties than magic-angle twisted bilayer graphene. Measurements of the Hall effect and quantum oscillations as a function of density and electric field enable us to determine the tunable phase boundaries of the system in the normal metallic state. Zero-magnetic-field resistivity measurements reveal that the existence of superconductivity is intimately connected to the broken-symmetry phase that emerges from two carriers per moiré unit cell. We find that the superconducting phase is suppressed and bounded at the Van Hove singularities that partially surround the broken-symmetry phase, which is difficult to reconcile with weak-coupling Bardeen-Cooper-Schrieffer theory. Moreover, the extensive in situ tunability of our system allows us to reach the ultrastrong-coupling regime, characterized by a Ginzburg-Landau coherence length that reaches the average inter-particle distance, and very large T_{BKT}/T_F values, in excess of 0.1 (where T_{BKT} and T_F are the Berezinskii-Kosterlitz-Thouless transition and Fermi temperatures, respectively). These observations suggest that MATTG can be electrically tuned close to the crossover to a two-dimensional Bose-Einstein condensate. Our results establish a family of tunable moiré superconductors that have the potential to revolutionize our fundamental understanding of and the applications for strongly coupled superconductivity.

REPORT

Electric field-tunable superconductivity in alternatingtwist magic-angle trilayer graphene

C Zeyu Hao^{1,*}, C A. M. Zimmerman^{1,*}, Patrick Ledwith¹, Eslam Khalaf¹, Danial Haie Najafabadi¹, C Kenji Watanabe², C Takashi Taniguchi³, ¹ Ashvin Vishwanath¹, ¹ Philip Kim^{1,†}

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+ These authors contributed equally to this work.

- Hide authors and affiliations

Science 12 Mar 2021: Vol. 371, Issue 6534, pp. 1133-1138 DOI: 10.1126/science.abg0399

System

- Alternating twists
- Sliding between layers N and N-2

PAPER · OPEN ACCESS

Electronic structure of lattice relaxed alternating twist tNGmultilayer graphene: from few layers to bulk AT-graphite

Nicolas Leconte¹, Youngju Park¹, Jiaqi An¹, Appalakondaiah Samudrala^{1,2} and Jeil Jung^{1,3} Published 31 August 2022 · @ 2022 The Author(s). Published by IOP Publishing Ltd

2D Materials, Volume 9, Number 4

Focus on Twistronics in 2D Materials

Citation Nicolas Leconte et al 2022 2D Mater. 9 044002

2 questions

- Energetic stability?

- Accuracy of analytical magic angle predictions?

Editors' Suggestion

Magic angle hierarchy in twisted graphene multilayers

Ac

Eslam Khalaf, Alex J. Kruchkov, Grigory Tarnopolsky, and Ashvin Vishwanath Phys. Rev. B 100, 085109 - Published 2 August 2019

Stability: locked into double commensurate AA-stacking

See Talk by Prof. G.J. Jung: Commensuration torques and lubricity in double moire systems

Eslam Khalaf, Alex J. Kruchkov, Grigory Tarnopolsky, and Ashvin Vishwanath Phys. Rev. B 100, 085109 - Published 2 August 2019

Magic angle numerical estimation: method

- Fix t2G magic angle at 1.08 degree using S
- Analytically estimate first magic for N>2 based on t2G coupling strength
- Calculate DOS for range of magic angles around this estimate (Lanczos recursion to tackle very large commensurate cells)
- Extract magic angle where DOS is largest`

Extracting the magic angle from DOS calculations

Magic angle reduction due to relaxation effects…

- Numerical magic angle (green) smaller than t2G-informed magic angle predictions (blue)
- Why…?

Magic angle reduction: explanation

$$
\alpha_k^{(n)} = \alpha^{(2)} / \left(2 \cos \frac{\pi k}{n+1} \right) \qquad \alpha_i = w_{AB} / (v_F k_D \theta_i)
$$

- Reduced AB' coupling strength (see red dotted line) when increasing twist angle (reduced lattice reconstruction)
- Magic angle happens at larger angle for larger N

Weaker coupling implies magic angle reduction

(In-plane relaxation degree of freedom contributes primarily)

$$
\kappa = w_{\rm AA}^{ij}/w_{\rm AB}^{ij}.
$$
\n
$$
r(r) = \sum_{j=0,\pm} e^{-iQ_j \cdot r} \left[\begin{pmatrix} \omega' & \omega e^{-i\phi_j} \\ \omega e^{i\phi_j} & \omega' \end{pmatrix} e^{-i\theta_j \cdot \tau_s} \right]
$$
\n
$$
\omega_{xx}(G_j) = H_{xx}(K; G_j)
$$

 $=\frac{1}{A_{M}}\int_{A_{M}}d\mathbf{r}\left[e^{i\mathbf{G}_{j}\cdot\mathbf{d}(\mathbf{r})}H_{XX'}\left(\mathbf{K}:\mathbf{d}(\mathbf{r})\right)\right]$

Take home message:

Reduction of magic angle values in tNG due to (in-plane) relaxation effects

PAPER • OPEN ACCESS

Electronic structure of lattice relaxed alternating twist tNGmultilayer graphene: from few layers to bulk AT-graphite

Nicolas Leconte¹, Youngju Park¹, Jiagi An¹, Appalakondaiah Samudrala^{1,2} and Jeil Jung^{1,3} Published 31 August 2022 · © 2022 The Author(s). Published by IOP Publishing Ltd

2D Materials, Volume 9, Number 4

Focus on Twistronics in 2D Materials

Citation Nicolas Leconte et al 2022 2D Mater. 9 044002

Effect of substrate on primary and secondary gaps in G on hBN

Motivation

Ab initio theory of moiré superlattice bands in layered twodimensional materials

Jeil Jung, Arnaud Raoux, Zhenhua Qiao, and A. H. MacDonald Phys. Rev. B 89, 205414 - Published 12 May 2014

Moiré band model and band gaps of graphene on hexagonal boron nitride

Jeil Jung, Evan Laksono, Ashley M. DaSilva, Allan H. MacDonald, Marcin Mucha-Kruczyński, and Shaffique Adam

Phys. Rev. B 96, 085442 - Published 30 August 2017

Origin of band gaps in graphene on hexagonal boron nitride

Jeil Jung ⊠, Ashley M. DaSilva, Allan H. MacDonald & Shaffique Adam ⊠

Nature Communications 6, Article number: 6308 (2015) Cite this article

Effective lattice model of graphene moiré superlattices on hexagonal boron nitride

Xianging Lin and Jun Ni Phys. Rev. B 100, 195413 - Published 12 November 2019

Accurate Gap Determination in Monolayer and Bilayer Graphene/ h-BN Moiré Superlattices

Hakseong Kim,^{†,§} Nicolas Leconte,^{‡,§} Bheema L. Chittari,[‡] Kenji Watanabe,^{||}® Takashi Taniguchi,^{||}
Allan H. MacDonald,[⊥] Jeil Jung,*^{,‡}® and Suyong Jung*^{,†}®

System

Primary and secondary gap: low angle regime

- Zero alignment: suspended G/h-BN shows largest gaps
- Increased rigidication of system: weak secondary gap reduction, large primary gap reduction
- Small increase of primary gap around 0.5 degree
- Relatively weak contribution of average mass-term gap to global gap value

Understanding the primary gap increase: local rotation angle

Red: against global rotation Blue: with global rotation

Simple shear strain

Strain fields in twisted bilayer graphene

Kazmierczak, Madeline Van Winkle, Colin Ophus, Karen C. Bustillo, Stephen Carr, Hamish G. Brown, Jim Ciston, Takashi Taniguchi, Kenji Watanabe & D. Kwabena Bediako

Nature Materials 20, 956-963 (2021) Cite this article

Understanding the primary gap increase: local rotation angle

Understanding the primary gap increase: local rotation angle

Increased local rotation at the AA (counter-clockwise) and AB stacking (clockwise) matches the larger lattice reconstruction for these angles.

Energetic stability?

Energetic stability

Large angle regime: robust 1 meV gap up to 30 degree

Take-home messages

- Substrate reduces the amplitude of the primary and secondary gaps in G-hBN
- Substrate causes larger lattice reconstruction away from perfect alignment
- Robust primary gap at large angle

Atomistic calculations of band gaps in graphene on hexagonal boron nitride

Jiaqi An, ^{1, 2} Nicolas Leconte,¹ Srivani Javvaji,¹ Youngju Park,¹ and Jeil Jung^{1, 2, 8}

¹Department of Physics, University of Seoul, Seoul 02504, Korea ²Department of Smart Cities, University of Seoul, Seoul 02504, Korea

Charge transfer in h-BN encapsulated BG

Motivations

interfacial ferroelectricity by stacking non-polar materials in a symmetry-breaking way

Unconventional ferroelectricity in moiré heterostructures

Zhiren Zheng, Qiong Ma Ξ , Zhen Bi, Sergio de la Barrera, Ming-Hao Liu, Nannan Mao, Yang Zhang, Natasha Kiper, Kenji Watanabe, Takashi Taniguchi, Jing Kong, William A. Tisdale, Ray Ashoori, Nuh Gedik, Liang Fu, Su-Yang Xu & Pablo Jarillo-Herrero

Nature 588, 71-76 (2020) Cite this article

Giant ferroelectric polarization in a bilayer graphene heterostructure

Ruirui Niu, Zhuoxian Li, Xiangyan Han, Zhuangzhuang Qu, Dongdong Ding, Zhiyu Wang, Qianling Liu, Tianyao Liu, Chunrui Han, Kenji Watanabe, Takashi Taniguchi, Menghao Wu, Qi Ren, Xueyun Wang, Jiawang Hong, Jinhai Mao, Zheng Han, Kaihui Liu, Zizhao Gan & Jianming Lu ⊠

Nature Communications 13, Article number: 6241 (2022) Cite this article

\exists T \angle 1V > cond-mat > arXiv:2102.12398

Condensed Matter > Mesoscale and Nanoscale Physics

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Submitted on 24 Feb 20211

Tunable ferroelectricity in hBN intercalated twisted double-layer graphene

Yibo Wang, Siqi Jiang, Jingkuan Xiao, Xiaofan Cai, Di Zhang, Ping Wang, Guodong Ma, Yaqing Han, Jiabei Huang, Kenji Watanabe, Takashi Taniguchi, Alexander S. Mayorov, Geliang Y

Electric field tunable layer polarization in graphene/boron-nitride twisted quadrilayer superlattices

Ziyan Zhu, Stephen Carr, Qiong Ma, and Efthimios Kaxiras Phys. Rev. B 106, 205134 - Published 21 November 2022

An atomistic approach for the structural and electronic properties of twisted bilayer graphene-boron nitride heterostructures

Min Long, Pierre A. Pantaleón, Zhen Zhan ⊠, Francisco Guinea, Jose Ángel Silva-Guillén & Shengjun Yuan \boxdot

npi Computational Materials 8, Article number: 73 (2022) Cite this article

\exists T \times 1V > cond-mat > arXiv:2211.16351

Condensed Matter > Mesoscale and Nanoscale Physics

[Submitted on 29 Nov 2022]

Strong gate-tunability of flat bands in bilayer graphene due to moiré encapsulation between hBN monolayers

Robin Smeyers, Lucian Covaci, Milorad V, Milošević

Types of system

Charge transfer in BG on hBN

BG/hBN

No charge transfer

Larger charge on contacting G layer Larger charge on remote G layer

Charge transfer in encapsulated systems

Energetic stability

Sliding-dependence of the charge transfer

$$
\Delta n = n_{L_3} - n_{L_2}\,\,[\text{eV/cm}^2]
$$

Red: more charge on layer 2

Blue: more charge on layer 3

Red: more charge on layer 2

Shared colormap range…

Blue: more charge on layer 3

Largest charge transfer

Red: more charge on layer 2

Blue: more charge on layer 3

$hBN / BG / hBN$

BG / hBN

Understanding…

Effect of rotation

- Twisting away from alignment: decoupling between layers
- At 5 degree, hBN barely has a charging effect
- Behavior is explained by respective contribution of individual hBN layers

Red: more charge on layer 2

Blue: more charge on layer 3

Effect of relaxation

Factor 2.5 increase in charge transfer

Take home message

Charge transfer from double moire can mostly be understood from single moire charge transfer contributions

Layer Polarization and Charge Transfer in h-BN Encapsulated Bilayer Graphene

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Conclusions

- The more accurate the force-field and tight-binding model parametrization, the better the quantitative comparison with experiment
- Lattice reconstruction affects the analytically predicted magic angles in tNG
- Substrate affects the primary and secondary angle-dependent gaps in G-hBN
- Charge transfer in encapsulated BG can be modulated by aligning the hBN layers in a parallel or antiparallel manner
- Methodology easily applicable for other layered materials

Thank you for your attention.

Questions?

Continuum and TB models

Continuum

$$
\mathcal{H}_{k} = \begin{pmatrix} H_{k}^{-} & T(r) & 0 & \cdots \\ T^{\dagger}(r) & H_{k'}^{+} & T^{\dagger}(r) & \cdots \\ 0 & T(r) & H_{k}^{-} & \\ \vdots & \vdots & \vdots & \ddots \end{pmatrix} + \Delta \epsilon_{1}
$$

bulk

 $\mathcal{H}_{\mathbf{k}}(k_z) = \begin{pmatrix} H_{\mathbf{k}}^- & 2T(\mathbf{r})\cos(k_z c_0) \\ 2T^{\dagger}(\mathbf{r})\cos(k_z c_0) & H_{\mathbf{k'}}^+ \end{pmatrix}$

$$
H_{\mathbf{k}}^{\pm} = \hbar v_F \begin{pmatrix} 0 & \pi_{\mathbf{k}}^{\pm} e^{\mp i \theta/2} \\ \pi_{\mathbf{k}} e^{\pm i \theta/2} & 0 \end{pmatrix}
$$

$$
T(\mathbf{r}) = \sum_{j=0,\pm} e^{-i \mathbf{Q}_j \cdot \mathbf{r}} \left[\begin{pmatrix} \omega' & \omega e^{-i \phi_j} \\ \omega e^{i \phi_j} & \omega' \end{pmatrix} e^{-i \mathbf{G}_j \cdot \mathbf{r}_s} \right]
$$

 $\Delta \epsilon = \text{diag}\left(-\frac{N-1}{2}, -\frac{N-1}{2} + 1, \ldots, +\frac{N-1}{2}\right) \cdot \frac{\Delta V}{N-1} \mathbb{1}$

Tight-binding
\n
$$
\hat{H} = \sum_{i}^{n_{at}} \epsilon_{i} |i\rangle\langle i| + \sum_{i,j}^{n_{at}} t_{ij} |i\rangle\langle j| \qquad |k\rangle = \frac{1}{\sqrt{n_{at}}} \sum_{j}^{n_{at}} e^{ik \cdot r_{j}} |j\rangle
$$
\n
$$
t_{ij} = t_{ij}^{\text{intra}} + t_{ij}^{\text{inter}}
$$
\n
$$
\begin{array}{c|c|c}\n & \text{arXiv:1910.12805} \\
\hline\n & \text{f2G2}\n\end{array}
$$
\n
$$
t_{\text{TC},ij} = V_{pp\pi}(r_{ij}) \left[1 - \left(\frac{c_{ij}}{r_{ij}}\right)^{2}\right] + V_{pp\sigma}(r_{ij}) \left(\frac{c_{ij}}{r_{ij}}\right)
$$
\n
$$
\begin{array}{c}\n\tau_{s} \\
\hline\n\tau_{\text{C},ij}}\n\end{array}
$$
\n
$$
V_{pp\pi}(r_{ij}) = V_{pp\pi}^{0} \exp\left(-\frac{r_{ij} - a_{0}}{r_{0}}\right)
$$
\n
$$
V_{pp\sigma}(r_{ij}) = V_{pp\sigma}^{0} \exp\left(-\frac{r_{ij} - c_{0}}{r_{0}}\right)
$$

$$
S = \frac{\theta_1 |t_{\text{eff}}|}{\omega} s = C_1 s
$$

 \overline{c}

Understanding charge distribution

Separate tNG multilayer Hamiltonian into smaller subsystems using basis of odd layer symmetric or even layer antisymmetric wave functions based on the eigenstates of opposite sign eigenvalues $\lambda_k = -\lambda_{N+1-k}$

k=2, states are on outer layers, thus weaker angle reduction effects

Mikito Koshino and Tsuneva Ando Phys. Rev. B 77, 115313 - Published 11 March 2008 Separation into elastic and potential energy maps

$$
E_i^{\text{el}} = \sum_{j \in \text{layer } i} \phi_{ij}
$$
\n
$$
E_i^{\text{pot}} = \sum_{j \notin \text{layer } i} \phi_{ij} = \sum_{j \in \text{any layer}} \phi_{ij} - E_i^{\text{el}}
$$
\n(A.1)

Extracted from LAMMPS:

- Get the atom-resolved energy maps
- Separate into elastic (only in-plane interactions) and potential (only out-of-plane pairwise interactions) during post-processing

- Layer and sublattice-resolved contributions
- Order of magnitude larger potential energy contribution: energetically favorable regions can be fully inferred from the potential energy
- Elastic energy shows the largest contributions in the SP regions when adding up all layer contributions
- L2 shows twice as large contributions compared to L1 and L3
- Chiral signatures are observed (add Ref 35, 36)

t4G maps

For increasing N, the trends can be inferred from N=3 and N=4 maps.

Magic angle predictions: explanations

- Remember: stronger coupling implies larger magic angle
- Largest drop for bulk: decreased coupling?
- Yes: distance increases from 3.313 Ang (AB stacked) to 3.328 Ang for bulk system at 2 degree. Why?
- Increasing AA contribution/weakening AB contribution for larger angle (weaker lattice reconstruction), increased estimates for average interlayer distance:

$$
\overline{c}_{ij}^{\text{bulk}} = r_{\text{AA}} c_0^{\text{AA}} + r_{\text{AB/BA}} c_0^{\text{AB/BA}} + r_{\text{SP}} c_0^{\text{SP}}
$$

Magic angle predictions: explanations

- N-dependence of average interlayer distance: converges to bulk value with increasing N
- Monotonic decrease for fixed outer layers (no out-of-plane relaxation)
- Gradual convergence when allowing for out-of-plane relaxation in case of free-standing configuration
- Minimum average distance at N=14 agrees with observed maximum angle for $N=10$
- Open question: how many layers to recover bulk behavior?

Electronic band structures up to N=6

- Modify S' to get the bandstructure for effective angle using reference commensurate angle
- Minimize band-width at Gamma
- Relaxation effect: el-hole asymmetry, separation of high energy bands from low energy bands at Gamma
- States are mostly located on the inner layers
- Layer asymmetry in DOS when applying electric field
- E-field: gap in the case of t4G

 $W_{\Gamma} = E_{\text{cond}}(\Gamma) - E_{\text{val}}(\Gamma)$

 $\theta_{\text{eff}} = \theta_{\text{ref}} - \delta \theta = \frac{S}{S'} \theta_{\text{ref}}$

 $S' = C'_1 s = C_1 \left(1 + \frac{\delta \theta}{\theta_{\text{ref}}} \right) \left(1 + \frac{\delta v_F}{v_F} \right) \left(\frac{\omega}{\omega + \delta \omega} \right) s.$

 $S = \frac{\theta_1 |t_{\text{eff}}|}{\omega} s = C_1 s$

Bulk mapping

Analogy with 1d-chain

$$
\lambda_k = 2\cos(\kappa_k),
$$

$$
\psi_k(\ell) = \sqrt{\frac{2}{N+1}}\sin(\kappa_k \ell)
$$

 $k = 1, 2, \cdots, N_e$

 $\ell = 1, 2, ..., N$ are the layer indices.

$$
\kappa_k = \pi k/(N+1)
$$

 0.015

0.010

0.005

0.000

 -0.005

 $-0.010 -$

К

 $\mathbb{E}\left(\mathrm{eV}\right)$

 $t2G$

 $t3G$

0.50

 $2.0\,$

 $\theta (^{\alpha})$

 $1.8\,$

 1.9

 θ ^{(\circ})

 $2.0\,$

0.200

 $t5G$

w

YL.

 $t4G$

 0.20

 0.15

Л'n.

 1.7

 1.8

v

٦.

 $t20G$